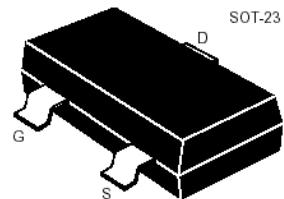


GMS2302

SOT-23 場效應晶體管(SOT-23 Field Effect Transistors)



N-Channel Enhancement-Mode MOS FETs

N 沟道增强型 MOS 场效应管

■MAXIMUM RATINGS 最大額定值

Characteristic 特性參數	Symbol 符號	Max 最大值	Unit 單位
Drain-Source Voltage 漏極-源極電壓	BV_{DSS}	16	V
Gate- Source Voltage 柵極-源極電壓	V_{GS}	± 8	V
Drain Current (continuous) 漏極電流-連續	I_D	2.6	A
Drain Current (pulsed) 漏極電流-脉沖	I_{DM}	10	A
Total Device Dissipation 總耗散功率 $T_A=25^\circ\text{C}$ 環境溫度為 25°C	P_D	450	mW
Junction 結溫	T_J	150	$^\circ\text{C}$
Storage Temperature 儲存溫度	T_{stg}	-55 to +150	$^\circ\text{C}$

■DEVICE MARKING 打標

GMS2302=A2

GMS2302

■ELECTRICAL CHARACTERISTICS 電特性

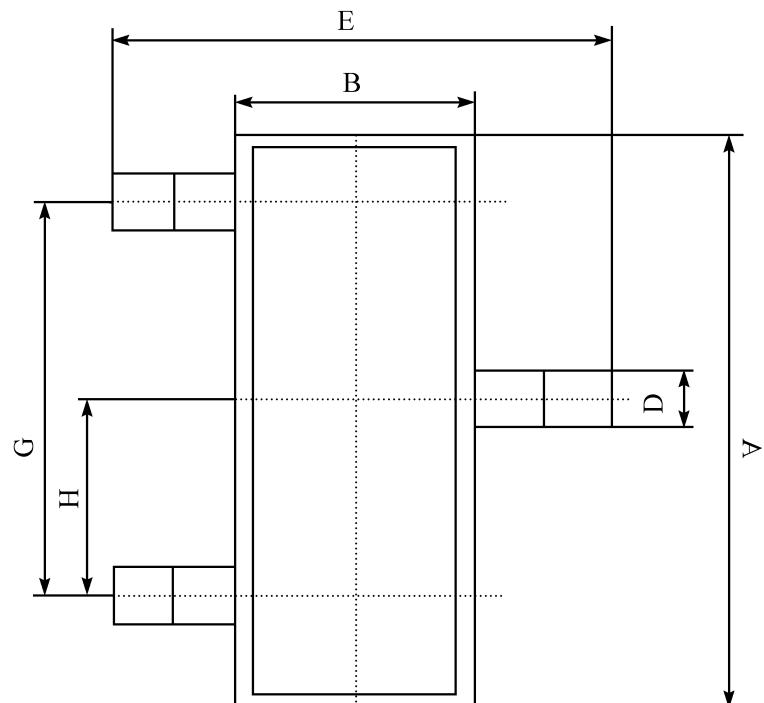
($T_A=25^\circ\text{C}$ unless otherwise noted 如無特殊說明，溫度為 25°C)

Characteristic 特性參數	Symbol 符號	Min 最小值	Typ 典型值	Max 最大值	Unit 單位
Drain-Source Breakdown Voltage 漏極-源極擊穿電壓($I_D = 250\mu\text{A}, V_{GS}=0\text{V}$)	BV_{DSS}	16	—	—	V
Gate Threshold Voltage 柵極開啓電壓($I_D = 250\mu\text{A}, V_{GS}= V_{DS}$)	$V_{GS(\text{th})}$	0.4	—	1.2	V
Drain-Source On Voltage 漏極-源極導通電壓($I_D = 50\text{mA}, V_{GS}= 5\text{V}$) ($I_D = 500\text{mA}, V_{GS}= 10\text{V}$)	$V_{DS(\text{ON})}$	—	—	0.375 3.75	V
Diode Forward Voltage Drop 內附二極管正向壓降($I_s= 0.75\text{A}, V_{GS}=0\text{V}$)	V_{SD}	—	—	1.2	V
Zero Gate Voltage Drain Current 零柵壓漏極電流($V_{GS}=0\text{V}, V_{DS}= 12\text{V}$) ($V_{GS}=0\text{V}, V_{DS}= 12\text{V}, T_A=55^\circ\text{C}$)	I_{DSS}	—	—	1 10	μA
Gate Body Leakage 柵極漏電流($V_{GS}=\pm 8\text{V}, V_{DS}=0\text{V}$)	I_{GSS}	—	—	± 100	nA
Static Drain-Source On-State Resistance 靜態漏源導通電阻($I_D=3\text{A}, V_{GS}=4.5\text{V}$) ($I_D=2\text{A}, V_{GS}=2.5\text{V}$)	$R_{DS(\text{ON})}$	—	—	0.09 0.13	Ω
Input Capacitance 輸入電容 ($V_{GS}=0\text{V}, V_{DS}= 6\text{V}, f=1\text{MHz}$)	C_{ISS}	—	—	880	pF
Common Source Output Capacitance 共源輸出電容($V_{GS}=0\text{V}, V_{DS}= 6\text{V}, f=1\text{MHz}$)	C_{OSS}	—	—	270	pF
Turn-ON Time 开啓時間 ($V_{DS}= 6\text{V}, I_D= 1\text{A}, R_{\text{GEN}}=6\Omega$)	$t_{(\text{on})}$	—	—	20	ns
Turn-OFF Time 關斷時間 ($V_{DS}= 6\text{V}, I_D= 1\text{A}, R_{\text{GEN}}=6\Omega$)	$t_{(\text{off})}$	—	—	65	ns

Pulse Width $\leq 300 \mu\text{s}$; Duty Cycle $\leq 2.0\%$

GMS2302

■DIMENSION 外形封裝尺寸



序號	數值及公差
A	2.90 ± 0.10
B	1.30 ± 0.10
C	1.00 ± 0.10
D	0.40 ± 0.10
E	2.40 ± 0.20
G	1.90 ± 0.10
H	0.95 ± 0.05
J	0.13 ± 0.05
K	$0.00-0.10$
M	≥ 0.2
N	0.60 ± 0.10
P	$7 \pm 2^\circ$

